

Supporting Information

Photocatalysis-induced Selective Decoration of Semiconducting Single Walled Carbon Nanotubes: Hole-doping Effect

Satoshi Kubota,^a Daisuke Shimamoto,^b Jin Sung Park,^b Hiromasa Nishikiori,^a Nobuaki Tanaka,^a Yoong Ahm Kim,^a Tsuneo Fujii,^{a,c} Morinobu Endo^{a,b} and Milred S. Dresselhaus^d

^aFaculty of Engineering, Shinshu University, Wakasato, Nagano 380-8553, E-mail: yak@endomoribu.shinshu-u.ac.jp; Fax: +81-26-269-5208; Tel: +81-26-269-5212;

^bInstitute of Carbon Science & Technology, Shinshu University, 4-17-1 Wakasato, Nagano 380-8553 (Japan)

^cNagano Prefectural Institute of Technology, Shimonogou, Ueda, Nagano 386-1211, Japan

^dMassachusetts Institute of Technology Cambridge, Massachusetts 02139-4307, USA

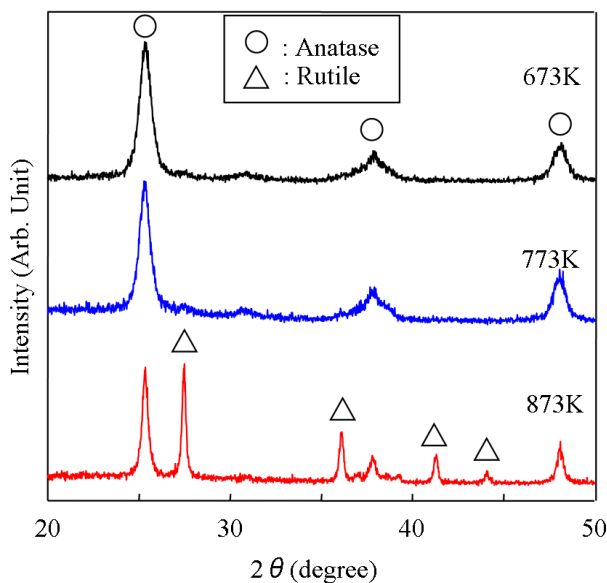


Figure S1. X-ray diffraction patterns of TiO₂ films that are prepared at different thermal treatment temperatures